

DATASHEET

Introduction



The DO311_20um_C3_1x4 product is a highperformance front side illuminated InGaAs PIN photodiode array with low capacitance, high responsivity, low dark current and proven excellent reliability. Designed with a 20 μ m detection window and 750um die-todie pitch, these products are tailored for long wavelength optical receiver applications with date rates up to 25Gbps at wavelengths from 1200nm to 1600nm with single mode fiber.

Key Features

- Excellent low dark current and capacitance
- -40C to 85C operation range
- 20µm detection window for enhanced optical alignment
- Front-side contact pads for flexible wire bonding
- Date rate up to 25Gbps/channel
- Highly robust, low-cost 4" IC wafer FAB with fast cycle-time
- Deliverable in GCS Known Good Die[™] with 100% testing and inspection
- RoHS compliant

Conditions Min. **Typical** Max. Unit **Notes Bandwidth** -3 V 30* GHz With TIA Wavelength range 910 1310/1550 1650 nm -5 V Capacitance -80.0 0.10 pF Responsivity @1310 nm 0.7 0.77 A/W Dark current -5V 0.3 3 nA

SPECIFICATIONS (T=25C)

ABSOLUTE MAXIMUM RATING

Parameter	Rating
Operating Temperature	-40C to 85C
Storage Temperature	-55C to 125C
Soldering Temperature	260C / 10 sec

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Applications

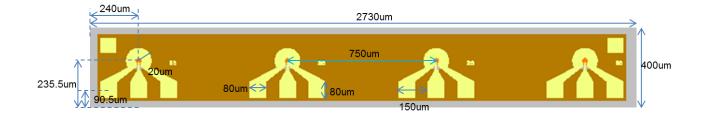
• 100G QSFP-LR



DIMENSIONS

	Conditions	Min.	Typical	Max.	Unit	Notes
Detection window			20		μm	
Die pitch			750		μm	
Bonding pad size			80x80		μm²	Ground pads
Metal height of bond pad		1.4	1.6		μm	Au metal
Die height		140	150	160	μm	
Die width		390	400	410	μm	
Die length			2730		μm	

BONDING PAD CONFIGURATION



P/N: DO311_20um_C3_1x4

Attention: Handle with care, InP is a brittle material. Avoid ESD; the device may be permanently damaged.

About GCS:

GCS is a world-class semiconductor manufacturer specializing in advanced photodiode technologies. We provide advanced GaAs and InGaAs photodiodes of varying data rate and application to multiple top tier optical transceiver customers throughout the world. With over 15 years' experience and over 150 million units delivered, our state of the art manufacturing facility has the capacity to produce 2,000 (100mm) wafers per month.

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